



SF1008DSU

SUPER FAST RECOVERY DIODE



VOLTAGE: 800 Volts

CURRENT: 10 Amperes

Package: TO-252

Marking And Polarity

FEATURES

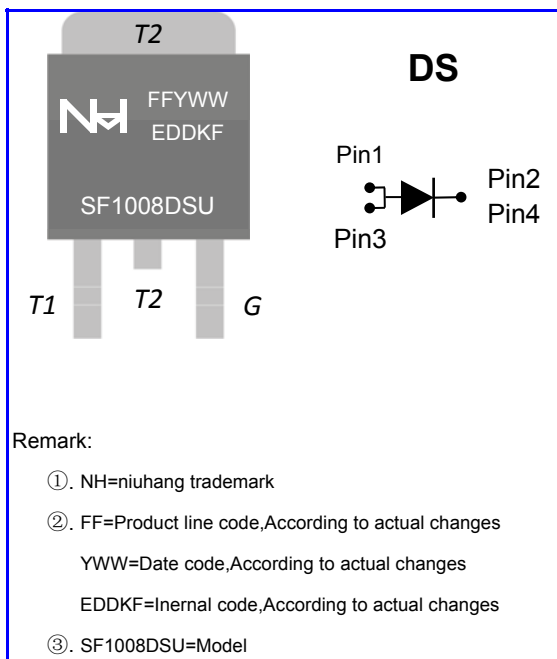
- Glass Passivated Chip Junction
- Low Forward Voltage Drop For High Efficiency
- Low Leakage Current For High Reliability
- High Forward Surge Capability For High Reliability
- Fast Reverse Recovery Time

MECHANICAL DATA

- **Package:** Molding Compound Meets UL 94 V-0 Flammability Rating, RoHS-Compliant
- **Polarity:** As Marked On Case
- **Mounting Position:** Any
- **Weight:** App. 0.321 Grams (0.01132 Ounce)

TYPICAL APPLICATIONS

- Typical Applications Are In Switching Power Supplies, High Frequency Converter, UPS, Freewheeling Diodes, PFC Boost And LED Driver Etc.



Single Phase, Half Wave, 60Hz, Resistive Or Inductive Load. For Capacitive Load, Derate Current By 20%

Maximum Ratings (Ta=25°C Unless otherwise specified)

Parameter	Test Conditions	Symbol	SF1008DSU	Unit
Maximum Repetitive Peak Reverse Voltage		V_{RRM}	800	V
Maximum RMS Voltage		V_{RMS}	560	V
Maximum DC Blocking Voltage		V_{DC}	800	V
Maximum Average Forward Rectified Current	@TC= 100 °C	$I_{F(AV)}$	10	A
Peak Forward Surge Current	8.3ms Single Half Sine-wave Superimposed On Rate Load	I_{FSM}	170	A
Current Squared Time Per Diode	$t < 8.3ms$	I^2t	119.9	A ² sec

Electrical Characteristics (Ta=25°C Unless otherwise specified)

Parameter	Test Conditions		Symbol	SF1008DSU			Unit
				Min.	Typ.	Max.	
Instantaneous forward voltage per diode (note1)	Ta=25°C	$I_F = 10.0 A$	V_F	--	1.70	2.20	V
	Ta=125°C			--	1.58	2.10	
Maximum DC Reverse Current at Rated DC Blocking Voltage (Note 1)	Ta=25°C	$V_R = V_{RRM}$	I_{RRM}	--	1	5	uA
	Ta=125°C	$V_R = 80\% * V_{RRM}$		--	50	500	
Typical Junction Capacitance Per Diode	4.0 V, 1MHz		C_J	--	50	--	pF
Maximum Reverse Recovery Time	$I_F = 0.5A, I_R = 1.0A, I_{RR} = 0.25A$		T_{RR}	--	--	50	nS

Thermal Characteristics (Ta=25°C Unless otherwise specified)

Parameter	Symbol	SF1008DSU	Unit
Operating Junction Temperature Range	T_J	-55 to 150	°C
Storage Temperature Range	T_{STD}	-55 to 150	
Typical thermal resistance (Note 2)	$R_{\theta JA}$	15	°C/W
	$R_{\theta JC}$	6	

Notes: 1. Pulse Test: 300 uS Pulse Width, 1% Duty Cycle

2. Device Mounted On Device Mounted On 10cm*10cm*1mm copper pad areas.

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Typical Characteristics Curves

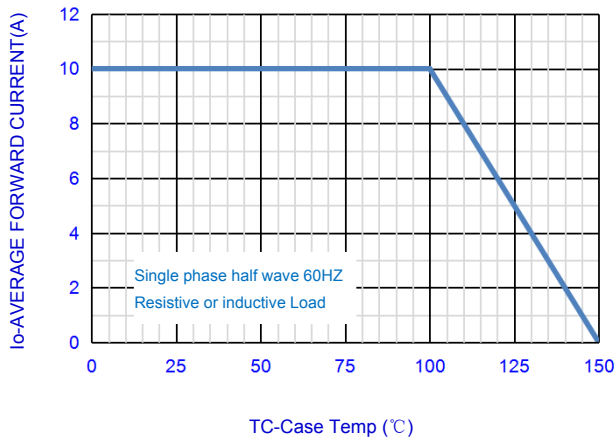


Fig.1-FORWARD CURRENT DERATING CURVE

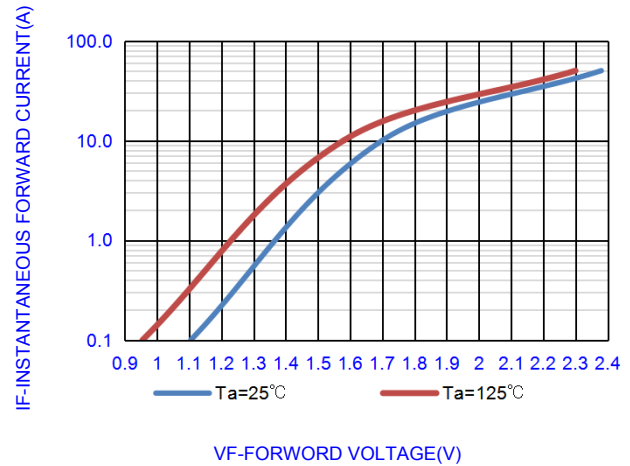


Fig.2- TYPICAL INSTANTANEOUS FORWARD

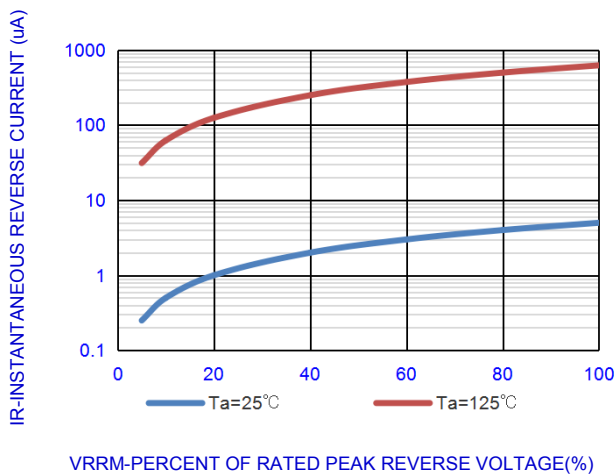


Fig.3- TYPICAL REVERSE CHARACTERISTICS

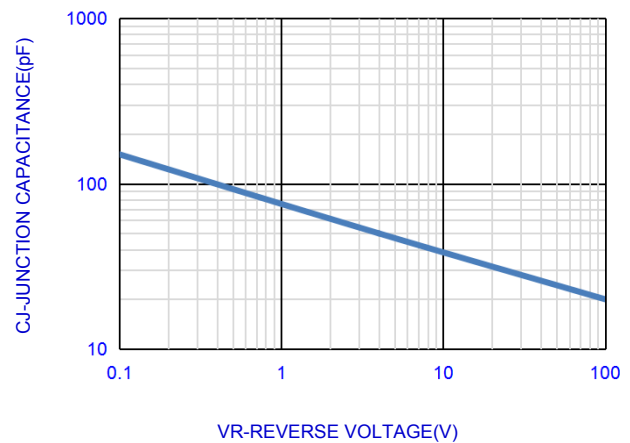


Fig.4- TYPICAL JUNCTION CAPACITANCE

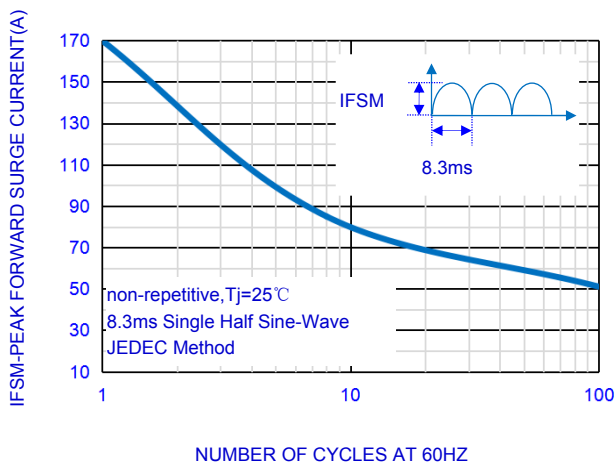


Fig.5-MAX. NON-REPETITIVE SURGE CURRENT

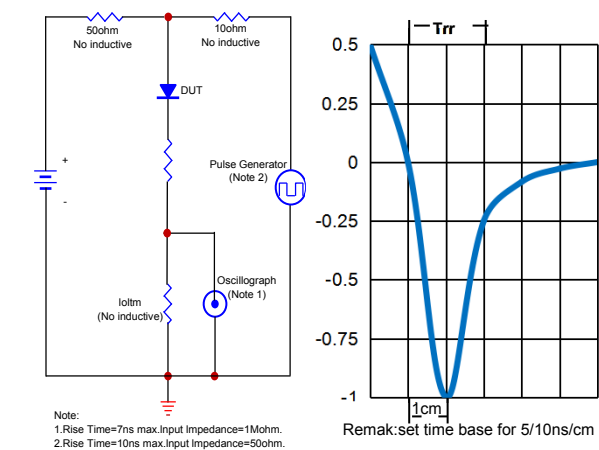


Fig.6-REVERSE RECOVERY TIME CHARACTERISTIC AND TEST CIRCUIT

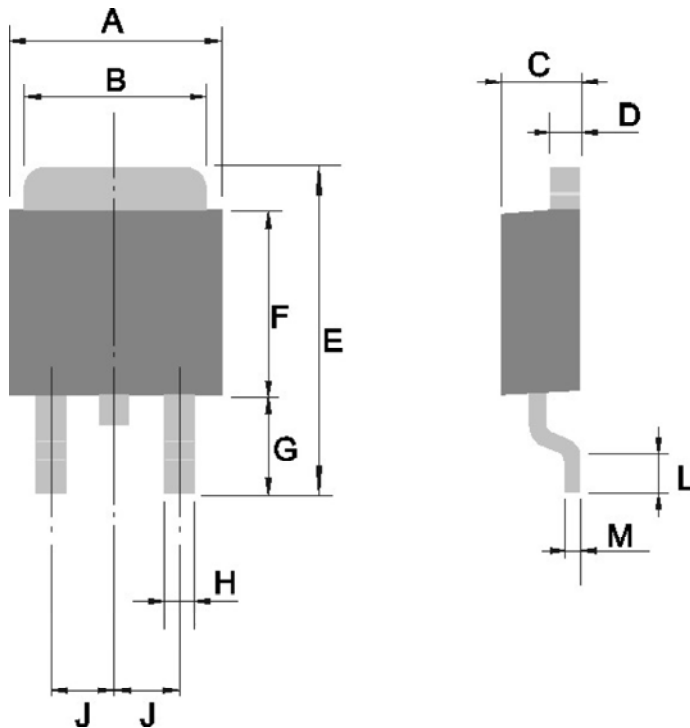
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OUTLINE DRAWINGS

TO-252

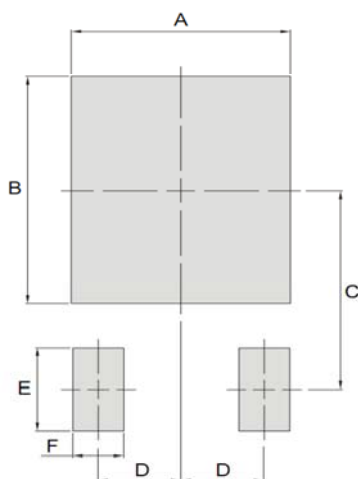


OUTLINE DIMENSIONS

Dim.	Milimeters			Inches		
	Min.	Typ.	Max.	Min.	Typ.	Max.
A	6.100	-	7.100	0.240	-	0.280
B	4.800	-	5.800	0.189	-	0.228
C	1.950	-	2.550	0.077	-	0.100
D	0.350	-	0.750	0.014	-	0.030
E	9.250	-	10.750	0.364	-	0.423
F	5.600	-	6.600	0.220	-	0.260
G	2.500	-	3.100	0.098	-	0.122
H	0.650	-	1.050	0.026	-	0.041
J	2.100	-	2.500	0.083	-	0.098
L	1.000	-	1.400	0.039	-	0.055
M	0.350	-	0.750	0.014	-	0.030

OUTLINE DRAWINGS

TO-252



OUTLINE DIMENSIONS

Dim.	Milimeters			Inches		
	Min.	Typ.	Max.	Min.	Typ.	Max.
A	-	6.09	-	-	0.24	-
B	-	7.57	-	-	0.298	-
C	-	6.64	-	-	0.261	-
D	-	2.3	-	-	0.091	-
E	-	2.76	-	-	0.109	-
F	-	1.42	-	-	0.056	-

PACKING INFORMATION

Package Code	Package Method	Inner Box Size L×W×H(mm)	Quantity (Pcs/Inner Box)	Outer Carton Size L×W×H(mm)	Quantity (Pcs/Carton)
TO-252	T/R	340×340×50	5000	360x360x260	25000

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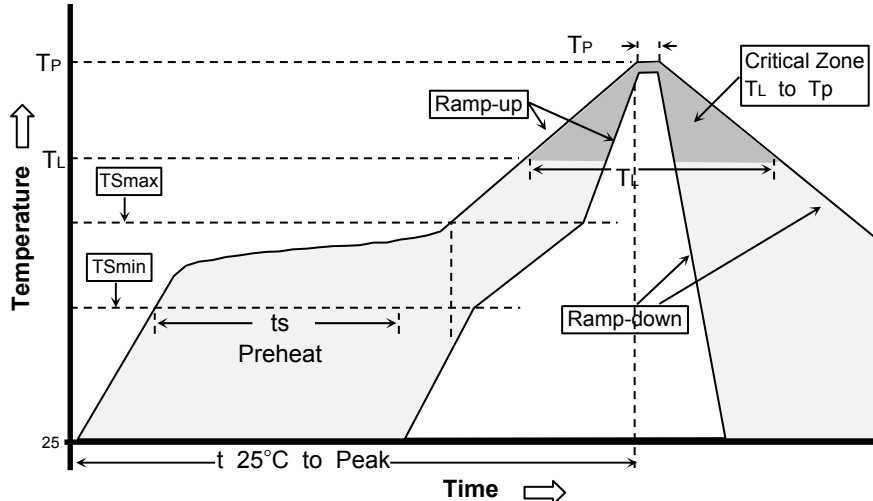
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Recommended wave soldering condition

Product	Peak Temperature	Soldering Time
Pb-free devices	260 +0/-5 °C	5 +1/-1 seconds

Recommended temperature profile for IR reflow



Profile feature	Sn-Pb eutectic Assembly	Pb-free Assembly
Average ramp-up rate (T _{smax} to T _p)	3°C/second max.	3°C/second max.
Preheat -Temperature Min(TS min) -Temperature Max(TS max) -Time(ts min to ts max)	100°C 150°C 60-120 seconds	150°C 200°C 60-180 seconds
Time maintained above: -Temperature (T _L) - Time (t _L)	183°C 60-150 seconds	217°C 60-150 seconds
Peak Temperature(T _P)	240 +0/-5 °C	260 +0/-5 °C
Time within 5°C of actual peak temperature(tp)	10-30 seconds	20-40 seconds
Ramp down rate	6°C/second max.	6°C/second max.
Time 25 °C to peak temperature	6 minutes max.	8 minutes max.

Note : All temperatures refer to topside of the package, measured on the package body surface.



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